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SJ

INDUSTRY STANDARD OF THE PEOPLE'S REPUBLIC OF CHINA

SJ/T 1472-2016

Replacing SJ 1472-1979

Discrete semiconductor devices 3CG110 high frequency low power silicon PNP transistor detailed specification

半导体分立器件 3CG110型硅PNP高频小功率晶体管详细规范

(English Translation)

Issued on: April 5, 2016 **Implemented on: September 1, 2016**

Issued by: Ministry of Industry and Information Technology

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What this standard covers

This standard specifies the external dimensions, maximum ratings and electrical characteristics, test conditions and inspection requirements for 3CG110 silicon PNP high frequency low power transistor devices.

Document data

Chinese classification (CCS): L42.

Estimated length of the Chinese original: 11,189 words.

Supersedes the earlier edition SJ 1472-1979.

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